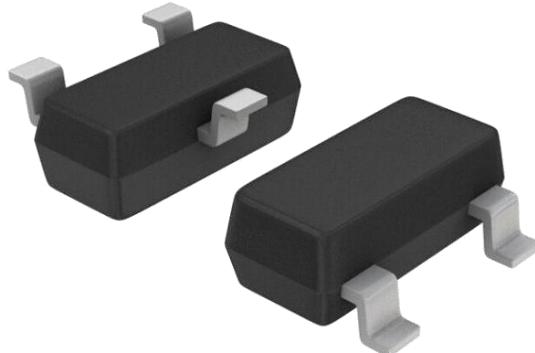




Features

- 500Watts peak pulse power ($t_p = 8/20\mu s$)
- Working Voltages: 5V, 8V, 12V, 15V, 24V and 36V
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- IEC 61000-4-2 $\pm 8kV$ contact $\pm 15kV$ air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 24A (8/20 μs)



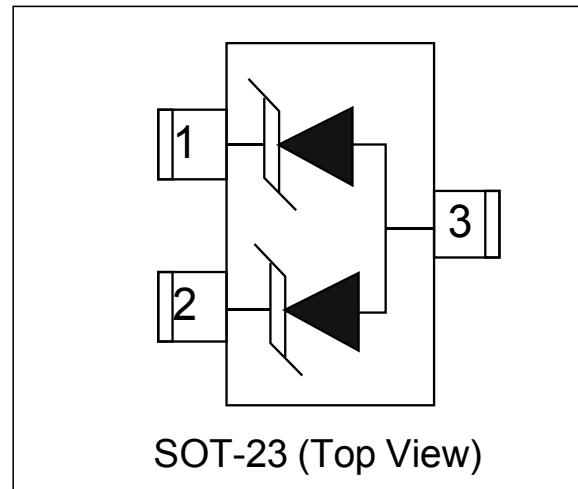
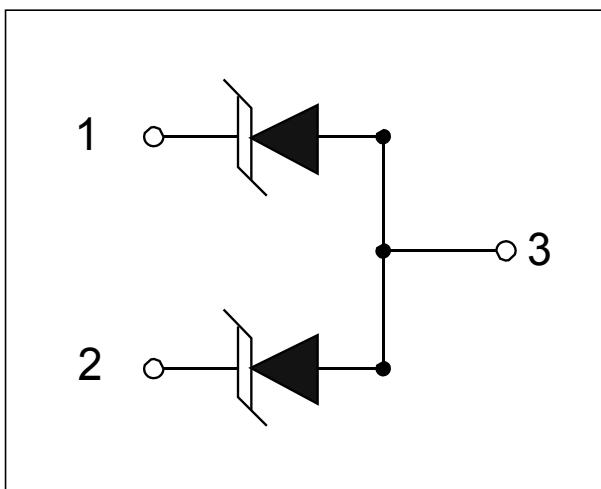
Applications

- RS-232, RS-422 & RS-423
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation
- Pagers Peripherals

Mechanical Data

- SOT-23 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Schematic & PIN Configuration





Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PP}	500	Watts
Peak Pulse Current ($t_p = 8/20\mu s$) (note1)	I_{PP}	24	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	8 15	kV
Lead Soldering Temperature	T_L	260(10seconds)	°C
Junction Temperature	T_J	-55 to + 150	°C
Storage Temperature	T_{stg}	-55 to + 150	°C

Electrical Characteristics

PESD05VS2UT

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				5.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	6.0			V
Reverse Leakage Current	I_R	$V_{RWM}=5V, T=25°C$			1.0	µA
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			45	A
Clamping Voltage	V_C	$I_{PP}=45A, t_p=8/20\mu s$		15		V
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$		325		pF

PESD08VS2UT

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				8.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	8.5			V
Reverse Leakage Current	I_R	$V_{RWM}=8V, T=25°C$			1.0	µA
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			35	A
Clamping Voltage	V_C	$I_{PP}=35A, t_p=8/20\mu s$		17		V
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$		240		pF



Electrical Characteristics

PESD12VS2UT

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				12.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$	13.3			V
Reverse Leakage Current	I_R	$V_{RWM}=12\text{V}, T=25^\circ\text{C}$			1.0	μA
Peak Pulse Current	I_{PP}	$t_p=8/20\mu\text{s}$			23	A
Clamping Voltage	V_C	$I_{PP}=23\text{A}, t_p=8/20\mu\text{s}$		22		V
Junction Capacitance	C_j	$V_R = 0\text{V}, f = 1\text{MHz}$		150		pF

PESD15VS2UT

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				15.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$	16.5			V
Reverse Leakage Current	I_R	$V_{RWM}=15\text{V}, T=25^\circ\text{C}$			1.0	μA
Peak Pulse Current	I_{PP}	$t_p=8/20\mu\text{s}$			17	A
Clamping Voltage	V_C	$I_{PP}=17\text{A}, t_p=8/20\mu\text{s}$		28		V
Junction Capacitance	C_j	$V_R = 0\text{V}, f = 1\text{MHz}$		90		pF

PESD24VS2UT

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				24	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$	26.0			V
Reverse Leakage Current	I_R	$V_{RWM}=24\text{V}, T=25^\circ\text{C}$			1.0	μA
Peak Pulse Current	I_{PP}	$t_p=8/20\mu\text{s}$			10	A
Clamping Voltage	V_C	$I_{PP}=10\text{A}, t_p=8/20\mu\text{s}$		44		V
Junction Capacitance	C_j	$V_R = 0\text{V}, f = 1\text{MHz}$		65		pF



Electrical Characteristics

PESD36VS2UT

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				36.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$	40.0			V
Reverse Leakage Current	I_R	$V_{RWM}=36\text{V}, T=25^\circ\text{C}$			1.0	μA
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu\text{s}$			8	A
Clamping Voltage	V_C	$I_{PP}=8\text{A}, t_p=8/20\mu\text{s}$		60		V
Junction Capacitance	C_j	$V_R = 0\text{V}, f = 1\text{MHz}$		50		pF

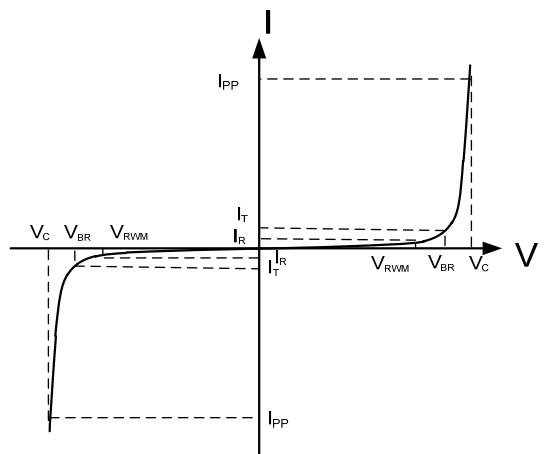
Note1: 8/20 μs pulse waveform.

Note2: C_j is measured from pin1/pin2 to pin3.



Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current



Note:.. 8/20μs pulse waveform.

Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

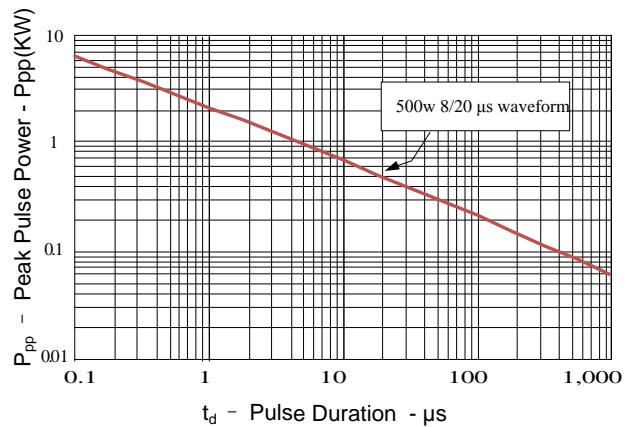


Figure 2: Power Derating Curve

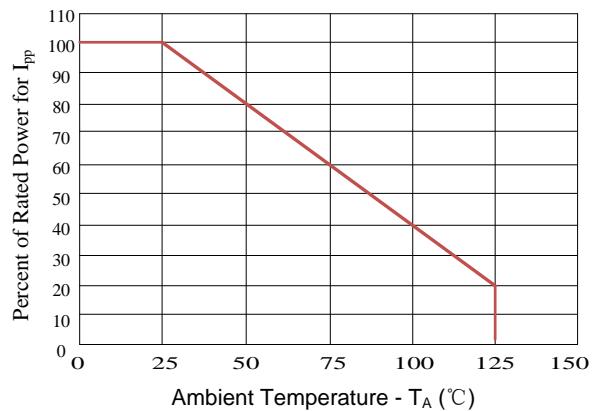


Figure 3: Pulse Waveform

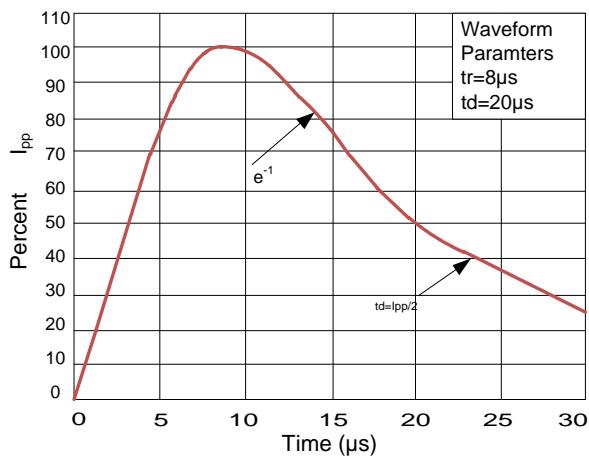
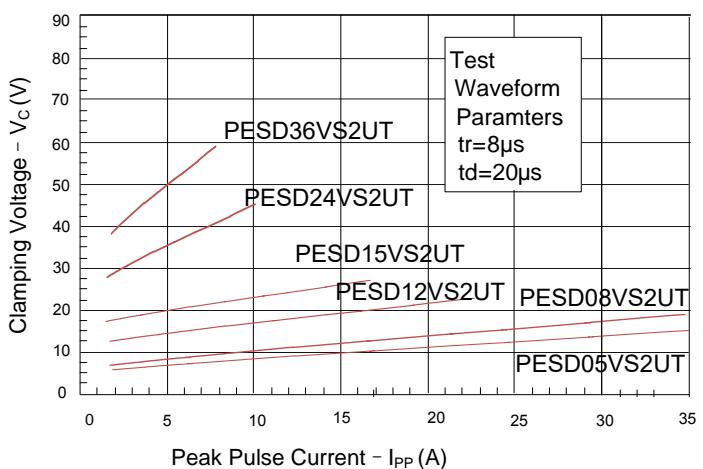
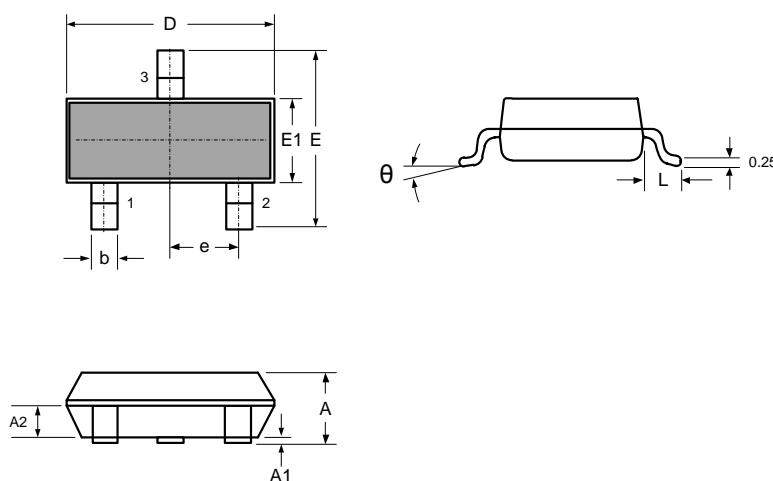


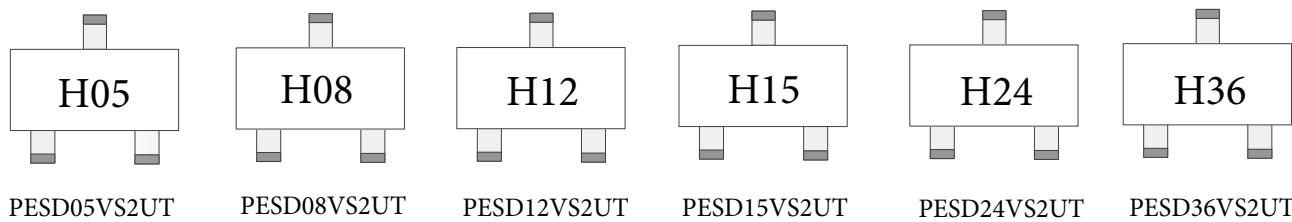
Figure 4: Clamping Voltage vs.I_{PP}





SYMBOL	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
D	2.800	3.000	0.110	0.118
b	0.300	0.500	0.012	0.020
E	2.250	2.550	0.089	0.100
E1	1.200	1.400	0.047	0.055
e	0.950 BSC		0.037 BSC	
L	0.300	0.500	0.012	0.020
θ	0	8°	0	8°

Marking



Ordering Information

Order code	Package	Base qty	Delivery mode
PESDxxVS2UT	SOT-23	3k	Tape and reel

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